NSN 5961-01-295-0934

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Fiig: A110a0



View Online at https://aerobasegroup.com/nsn/5961-01-295-0934 **Inclosure Material:** Metal **Overall Length:** 1.563 inches **Overall Height:** Between 0.250 inches and 0.450 inches Overall Width: Between 0.990 inches and 1.050 inches **Mounting Facility Quantity:** 2 **Internal Configuration:** Junction contact-darlington connected **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 5.0 emitter to base voltage, static, collector open and 100.0 collector to base voltage/static/emitter open and 100.0 collector-to-emitter, substaining voltage, base open-circuited **Current Rating Per Characteristic:** 50.00 amperes zero-gate-voltage source current blank and 1.00 amperes zero-gate-voltage source current of standard range **Power Rating Per Characteristic:** 300.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 125.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: npn **Terminal Type And Quantity:** 1 case and 2 pin Shelf Life: N/a **Unit Of Measure: Demilitarization:** No